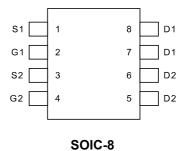


#### Dual P-Channel Enhancement Mode MOSFET

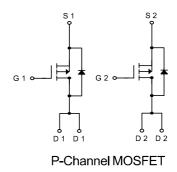
#### **Description**

The SM4953 uses advanced trench technology to provide excellent  $R_{\text{DS(ON)}}$  and low gate charge. The two MOSFETs make a compact and efficient switch and synchronous rectifier combination for use in buck converters.



#### **General Features**

- -30V/-4.9A,  $R_{DS(ON)} = 53m\Omega(typ.)$  @  $V_{GS} = -10V$  $R_{DS(ON)} = 80m\Omega(typ.)$  @  $V_{GS} = -4.5V$
- Super High Density Cell Design
- Reliable and Rugged
- SO-8 Package



## **♦** Ordering Information

Ordering Number		Daakawa	Pin Assignment						Dooking	
Lead Free	Halogen Free	Package	1	2	3	4	5	6 7	8	Packing
SM4953PRL	SM4953SRG	SOP-8	S1	G1	S2	G2	D1	D1 D2	D2	Tape Reel
(1)Packa (2)Packir (3)Lead I	ng Type	X X  T	(2)		Тар	e R		ee; L	: Le	ead Free



### ◆ Absolute Maximum Ratings (T<sub>A</sub>=25°C, unless otherwise noted)

Symbol	Parameter	Rating	Unit
$V_{DSS}$	Drain-Source Voltage	-30	V
$V_{GSS}$	Gate-Source Voltage	±25	V
I <sub>D</sub> *	Maximum Drain Current – Continuous T <sub>A</sub> = 25°C	-4.9	۸
I <sub>DM</sub>	Maximum Drain Current – Pulsed	-30	^

a:Fused current that based on wire numbers and diameter

b:Repetitive Rating: Pulse width limited by the maximum junction temperature

### ♦ Electrical Characteristics (T<sub>A</sub>=25°C, unless otherwise noted)

Cumbal	B	Tank Camalikian		SM4953			
Symbol	Parameter	Test Condition	Min.	Typ <sup>a</sup> .	Max.	Unit	
Static							
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>DS</sub> =-250μA	-30			V	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-24V , V <sub>GS</sub> =0V			-1	μΑ	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ , $I_{DS}$ =-250 $\mu$ A	-1	-1.5	-2	V	
GSS	Gate Leakage Current	V <sub>GS</sub> =±25V , V <sub>DS</sub> =0V			±100	nA	
R <sub>DS(ON)</sub>	Drain-Source On-state Resistance <sup>b</sup>	V <sub>GS</sub> =-10V , I <sub>DS</sub> =-4.9A		53	60	mΩ	
		V <sub>GS</sub> =-4.5V , I <sub>DS</sub> =-3.6A		80	95		
V <sub>SD</sub>	Diode Forward Voltage <sup>b</sup>	I <sub>SD</sub> =-1.7A , V <sub>GS</sub> =0V		-0.7	-1.3	V	
Dynamic <sup>a</sup>	•	•	•	•			
Qg	Total Gate Charge	V <sub>DS</sub> =-15V , I <sub>GS</sub> =-10V		22.3	29		
$Q_{gs}$	Gate-Source Charge	I <sub>D</sub> =-4.6A		4.65		nC	
$Q_{gd}$	Gate-Drain Charge			2		1	
t <sub>d(ON)</sub>	Turn-on Delay Time	V <sub>DD</sub> =-15V , I <sub>D</sub> =-2A .		10	18		
Tr	Turn-on Rise Time	$V_{GEN}$ =-10V , $R_G$ =6 $\Omega$		15	20	ns	
t <sub>d(OFF)</sub>	Turn-off Delay Time			22	38		
$T_f$	Turn-off Fall Time	$R_L=7.5\Omega$		15	25		
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> =0V		1260			
Coss	Output Capacitance	V <sub>DS</sub> =-25V		340		pF	
C <sub>rss</sub>	Reverse Transfer Capacitance	Frequency=1.0MHz		220			

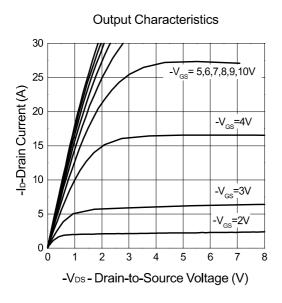
Note: Pulse Test: Pulse Width ≤300us, Duty Cycle≤2%

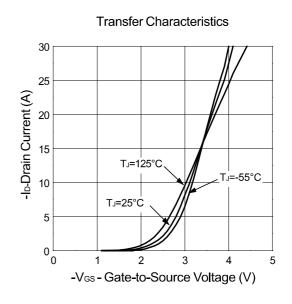
d: Guaranteed by design: not subject to production testing

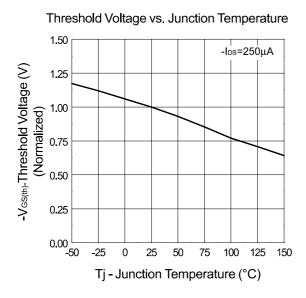
c:1-in<sup>2</sup> 2oz Cu PCB board

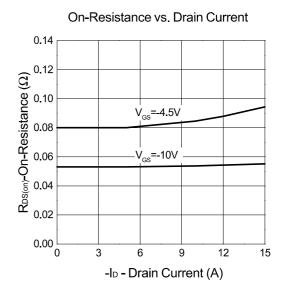


## **Typical Characteristics**



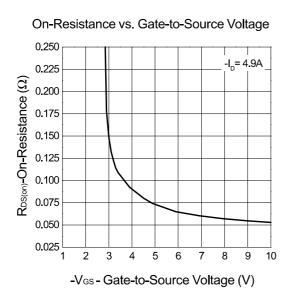


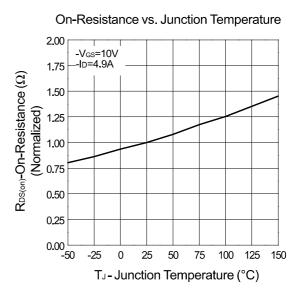


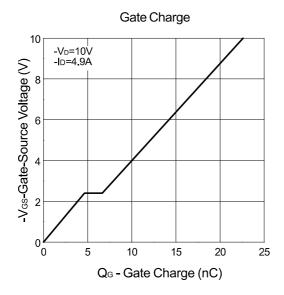


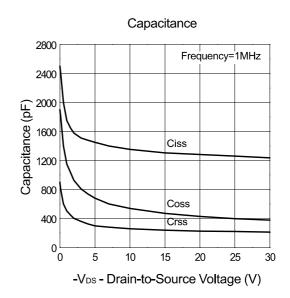


# **Typical Characteristics (Cont.)**



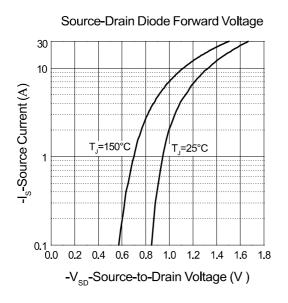


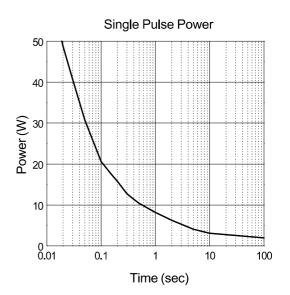




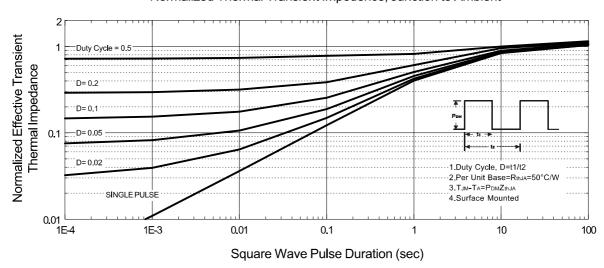


# **Typical Characteristics (Cont.)**





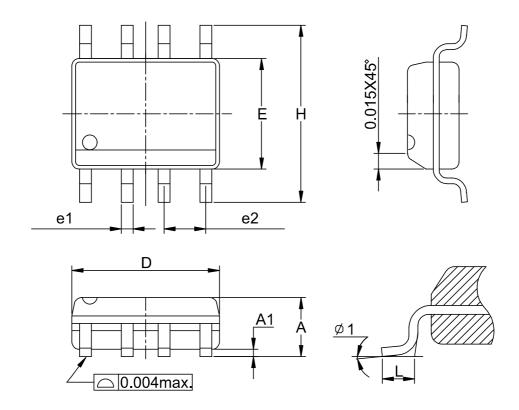
#### Normalized Thermal Transient Impedence, Junction to Ambient





# **Packaging Information**

SOP-8 pin ( Reference JEDEC Registration MS-012)



Dim	Millim	neters	Inches			
Dim	Min. Max.		Min.	Max.		
А	1.35	1.75	0.053	0.069		
A1	0.10	0.25	0.004	0.010		
D	4.80	5.00	0.189	0.197		
E	3.80	4.00	0.150	0.157		
Н	5.80	6.20	0.228	0.244		
L	0.40	1.27	0.016	0.050		
e1	0.33	0.51	0.013	0.020		
e2	1.27	1.27BSC		BSC		
ф 1	8	0	8°			

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RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3 2SK2614(TE16L1,Q)